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	CN Number:		807110	01		PCN D	ate:	Ju	ly :	16, 201	.8	
	tle: Datasheet fo	r LP88	363-Q1								1	
Cu	stomer Contact:	PCN	Manage	<u>er</u>					De	pt:	Quality	Services
Ch	nange Type:											
	Assembly Site				Design					Wafer	Bump S	Site
	Assembly Process	;		\boxtimes	Data Shee	et				Wafer	Bump N	1aterial
	Assembly Materia	ls			Part numl	ber char	nge			Wafer	Bump F	rocess
	Mechanical Specif	ication			Test Site					Wafer	Fab Site	е
	Packing/Shipping,	/Labeli	ng		Test Proce	ess				Wafer	Fab Mat	terials
										Wafer	Fab Pro	cess
				N	otification	on De	tails					
De	escription of Chan	ge:										
	xas Instruments Inc								no	tificatio	on.	
	e product datasheet						ed belo	w.				
Th	e following change	history	provide	es '	further det	ails.						
4	ŢEXAS											LP8863-Q1
•	INSTRUMENTS								SNV	SAB6BI-M	ARCH 2017-	REVISED JULY 2018
Ch	nanges from Revision A	(June 20	17) to Re	vis	ion B							Page
	Added top navigator link	for TI ref	ference de	esia	n							1
:	Added top navigator link Added note "When interr											
:	Added top navigator link Added note "When interr as VDD."	nal charg	e pump is	dis	abled and CP	UMP pin i	is used a	s an	inpu	ıt, max ra	ating is 5.5	V same
:	Added note "When interras VDD."Added note "When interr	nal charg nal charg	e pump is e pump is	dis	abled and CP	PUMP pin i	s used a	s an s s an	inpu inpu	ıt, max ra ıt, max ra	ating is 5.5 ating is 5.5	V same 7 V same
:	Added note "When interras VDD."	nal charg nal charg	e pump is e pump is	dis	abled and CP	PUMP pin i	is used a	s an s an	inpu	ıt, max ra ıt, max ra	ating is 5.5	V same 7 V same 7
:	Added note "When interras VDD." Added note "When interras VDD." Deleted "fosc" row	nal charg	e pump is	dis	abled and CP	PUMP pin i	s used a	s an s an	inpu	ıt, max ra ıt, max ra	ating is 5.5	V same
	Added note "When interras VDD."	nal charg	e pump is e pump is 	dis	abled and CP	PUMP pin i	is used a	s an	inpu	ıt, max ra ıt, max ra	ating is 5.5	V same
	Added note "When interras VDD." Added note "When interras VDD." Deleted "fosc" row Deleted "led_driver_head Changed to "325" from "2	nal charg	e pump is e pump is	dis	abled and CP	PUMP pin i	is used a	s an	inpu	ıt, max ra	ating is 5.5	V same
	Added note "When interras VDD."	nal charg nal charg droom = 0	e pump is e pump is	dis	abled and CP	PUMP pin i	is used a	s an	inpu	ıt, max ra	ating is 5.5	V same
	Added note "When interras VDD." Added note "When interras VDD." Deleted "fosc" row Deleted "led_driver_head Changed to "325" from "3 Changed to "450" from "4	nal charg nal charg droom = 1 200" 400"	e pump is e pump is	dis	abled and CP	PUMP pin i	is used a	s an	inpu	ut, max ra	ating is 5.5	V same
	Added note "When interras VDD." Added note "When interras VDD." Deleted "fosc" row Deleted "led_driver_head Changed to "325" from "4 Changed to "450" from "4 Changed to "18.6" from "4 Changed to "21.4" from "4	nal charg nal charg droom = 1 200" 400" 118.8"	e pump is e pump is	dis	abled and CP	PUMP pin i	is used a	s an	inpu	ut, max ra	ating is 5.5	V same
:	Added note "When interras VDD." Added note "When interras VDD." Deleted "fosc" row Deleted "led_driver_head Changed to "325" from "3 Changed to "450" from "4	nal charg nal charg droom = 1 200" 400" 118.8" 121.2"	e pump is e pump is 01b"	dis	abled and CP	PUMP pin i	is used a	s an	inpu	ut, max ra	ating is 5.5	V same
:	Added note "When interras VDD." Added note "When interras VDD." Deleted "fosc" row Deleted "led_driver_head Changed to "325" from "2 Changed to "450" from "4 Changed to "21.4" from "4 Added VSDO _{OL} and VSD	droom = 1200"	e pump is e pump is 01b"	i dis	abled and CP sabled and CP	PUMP pin i	s used a	s an	inpu	ut, max ra	ating is 5.5	V same
:	Added note "When interras VDD." Added note "When interras VDD." Deleted "fose" row Deleted "led_driver_head Changed to "325" from "3 Changed to "450" from "4 Changed to "18.6" from " Changed to "21.4" from " Added VSDO _{OL} and VSD Changed Data hold time Changed to "VDD" from "4	droom = (200"	e pump is e pump is 01b" rowse rowse	i dis	abled and CP sabled and CP	PUMP pin i	s used a	s an	inpu	ut, max ra	ating is 5.5	V same
:	Added note "When interras VDD." Added note "When interras VDD." Deleted "fosc" row Deleted "led_driver_head Changed to "325" from "2 Changed to "450" from "4 Changed to "18.6" from " Changed to "21.4" from " Added VSDO _{OL} and VSD Changed Data hold time	nal charg nal charg droom = 1 200" 400" 118.8" 121.2" 100 _{0H} two to rising "EN"	e pump is e pump is 01b"	dis	abled and CP	PUMP pin i	is used a	s an	inpu	ut, max ra	ating is 5.5	V same
:	Added note "When interras VDD." Added note "When interras VDD." Deleted "fosc" row Deleted "led_driver_head Changed to "325" from "3 Changed to "450" from "4 Changed to "18.6" from "4 Changed to "21.4" from "4 Added VSDO _{OL} and VSD Changed Data hold time Changed to "VDD" from "6 Changed to "90%" from "6	nal charg nal charg droom = 1200" 400" 118.8" 121.2" 100 _{OH} two to rising "EN" 188%"	e pump is e pump is 01b"	dis	abled and CP	PUMP pin i	is used a	s an	inpu	ut, max ra	ating is 5.5	V same
:	Added note "When interras VDD." Added note "When interras VDD." Deleted "fosc" row Deleted "led_driver_head Changed to "325" from " Changed to "450" from " Changed to "21.4" from " Added VSDO _{OL} and VSE Changed Data hold time Changed to "VDD" from " Changed to "90%" from " Changed to "1.21 V" from "	droom = 1200"	e pump is e pump is 01b"	dis	abled and CP	PUMP pin i	s used a	s an	inpu	ıt, max ra	ating is 5.5	V same
:	Added note "When interras VDD."	droom = 1200"	e pump is e pump is 01b" o rows edge of S	dis	abled and CP	PUMP pin i	s used a	s an	inpu	ıt, max ra	ating is 5.5	V same
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•	Changed to "DITHER_SELECT[2:0]" from "DITHER_SELECT	CT[1:0]"		29
7.	Changed to "110 ms" from "1600 milliseconds"			
	Changed to "overcurrent" from "undervoltage"			
•	Changed to "Boost does not start up. Fault is cleared by VD from "Device starts up using fail-safe values."	DD cycling with correct res	istor connection at FSET pin."	
•	Changed to "400-ms" from "300-ms"			
	Changed to "VDD" from "EN"			. 39
•	any time after EN low."			41
	Changed to "8B0h' from "B0h"			
	Changed to "R/W-2h' from 'R/W-0h"			
	Changed to "2h" from "0h"			
	Changed to "100h" from "0h"			
	Changed to "100h" from "0h"			
	Changed to "100h" from "0h"			
•	Changed to "100h" from "0h"			
•	Changed to "000h - 0FFh = 0 °C to 255 °C, 100h - 1FFh = -			
	Changed to "000h - 0FFh = 0 °C to 255 °C, 100h - 1FFh = -			
•	Changed to "000h - 0FFh = 0 °C to 255 °C, 100h - 1FFh = -			
•	Changed to "1C0h" from "0h"			. 63
	Changed to "1C0h" from "0h"	***************************************		. 63
•	Changed to "1C0h" from "0h"			. 63
•	Changed to "1C0h" from "0h"			. 64
	Changed to "2882h" from "882h"			. 64
	Changed to "2h" from "0h"			. 64
•	Changed to "2h" from "0h"			. 64
•	Changed Description of FSM_LIVE_STATUS			. 65
•	Changed to " $V_{IN(min)} \times D / (f_{SW} \times L)$ " from " $V_{IN(min)} \times D / f_{SW}$	x L"		. 70
•	Changed to "Current set resistor for 100 mA maximum" from	m "Maximum current set re	esistor"	73
•	Changed to "43.5 V" from "40 V"			. 75
•	Changed to "10-µF" from "10-µH"			. 78
•	Changed to "Current set resistor for 150 mA max" from "Ma	aximum current set resisto	r"	80
Th	a datacheet number will be changing			
	e datasheet number will be changing. Device Family Cha	inge From:	Change To:	$\overline{}$
٦	-			
LI	P8863-Q1 SNV	/SAB6A	SNVSAB6B	

These changes may be reviewed at the datasheet links provided.

http://www.ti.com/product/LP8863-Q1

Reason for Change:

To accurately reflect device characteristics.

Anticipated impact on Fit, Form, Function, Quality or Reliability (positive / negative):

No anticipated impact. This is a specification change announcement only. There are no changes to the actual device.

Changes to product identification resulting from this PCN:

None.

Product Affected:

LP8863ADCPRQ1		
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For questions regarding this notice, e-mails can be sent to the regional contacts shown below or your local Field Sales Representative.

Location	E-Mail
USA	PCNAmericasContact@list.ti.com
Europe	PCNEuropeContact@list.ti.com
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